NSN 5961-01-275-8264

Transistor - Page 1 of 1

A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-275-8264 **Inclosure Material:** Ceramic **Overall Length:** Between 0.965 inches and 0.985 inches **Function For Which Designed:** Amplifier **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 breakdown voltage, collector-to-emitter, base open and 100.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 100.0 breakdown voltage, collector-to-base, emitter open and 4.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 16.00 amperes all primaries **Transfer Ratio:** 10.0 static forward current transfer ratio, common-emitter and 32.0 static forward current transfer ratio, common-emitter **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: